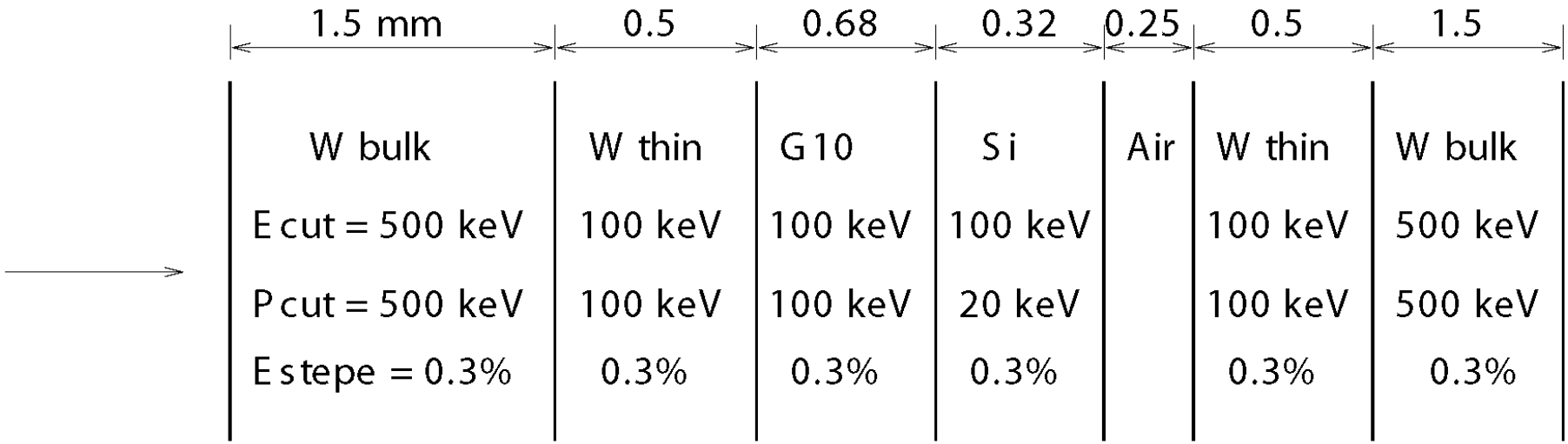
Some EGS Studies…

- Compare with Geant4
  - Questions of range/cutoff
- EM Resolution understood?

- Moliere radius – readout gap relation
- Input shower widths for fast MC

- Calibration requirement (electronics design)
- ECal depth
  - containment
  - Transverse/long. segmentation for pattern recognition
  - Optimize coarser sampling with depth
- Minimum number of silicon layers (30? 25? 20??)

EGS4 Setup



Config: 30 x [5/7 X0 (2.5 mm) + 1.25 mm gaps]

Thin EM sampling (Si)

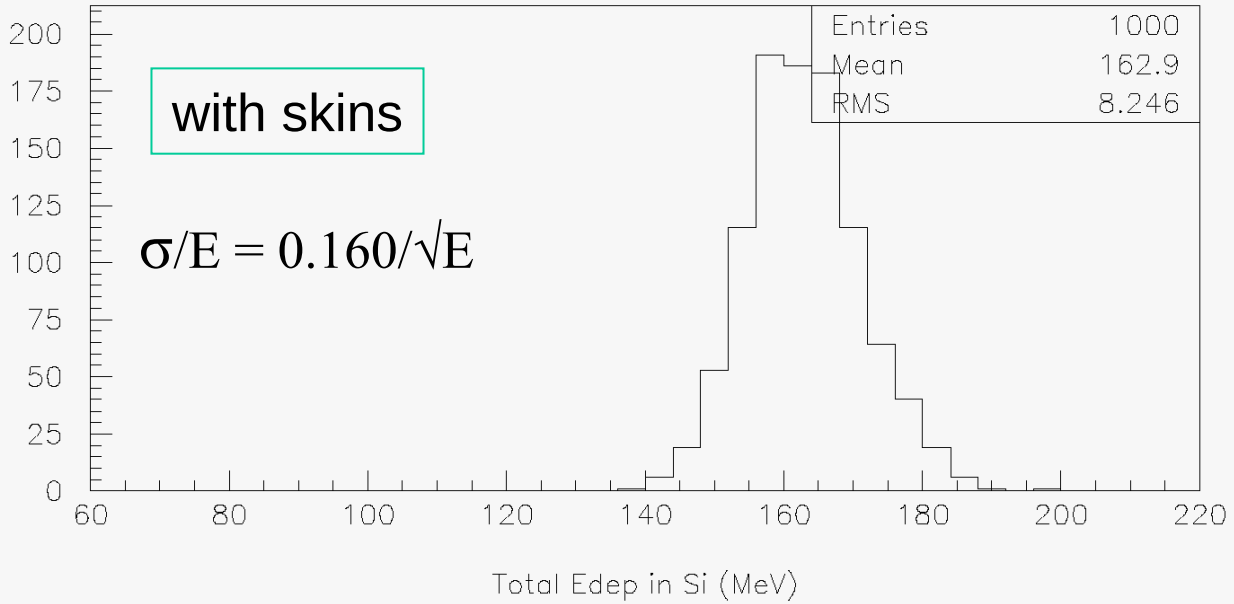
If energy cutoffs (EGS) are too large, then the simulated range of low energy secondaries exceeds the physical range

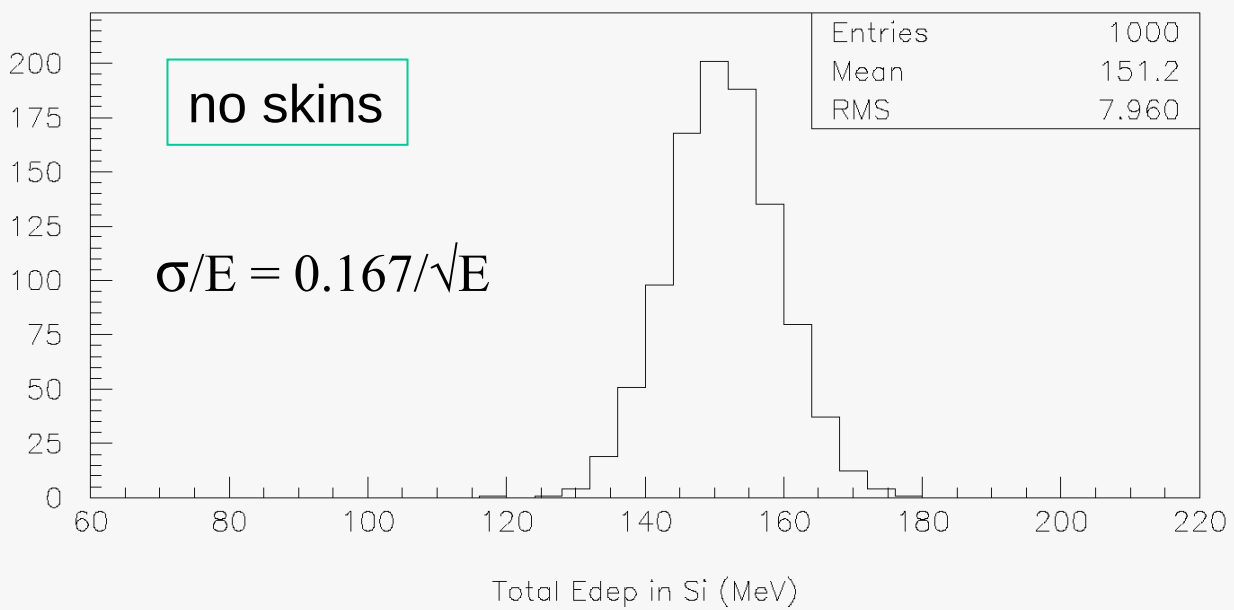
$\Rightarrow$ Their energy doesn't get deposited in the sensitive region.

Presumably the same issue exists for Geant4 (range cut)

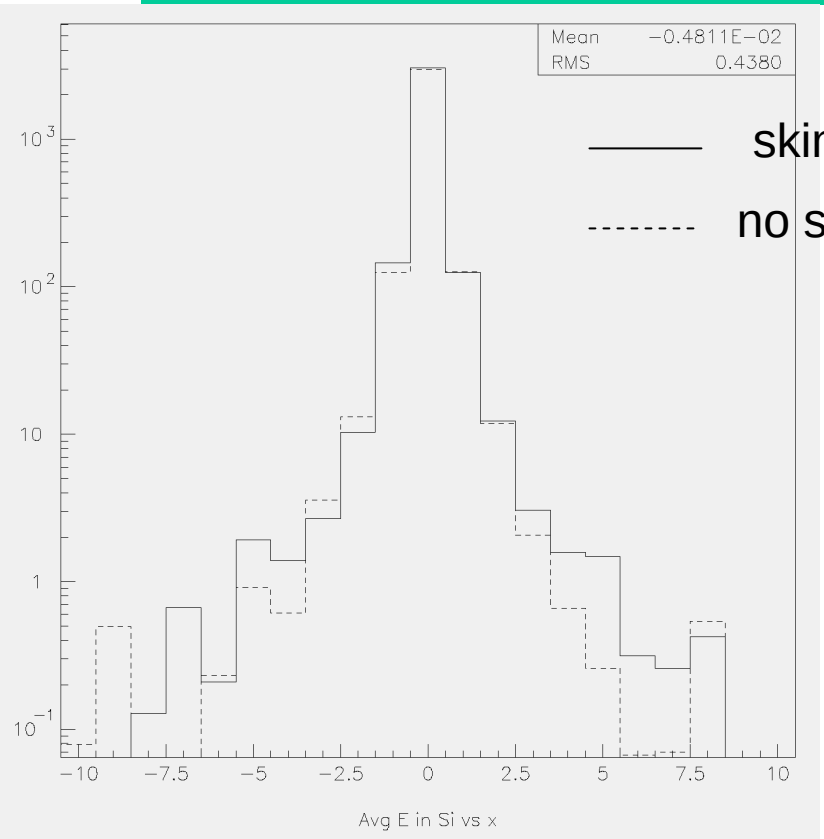
Do we need the “skins” in this case?

- 10 GeV photons
- about 3x more CPU time





transverse spatial distributions (5 GeV photons)

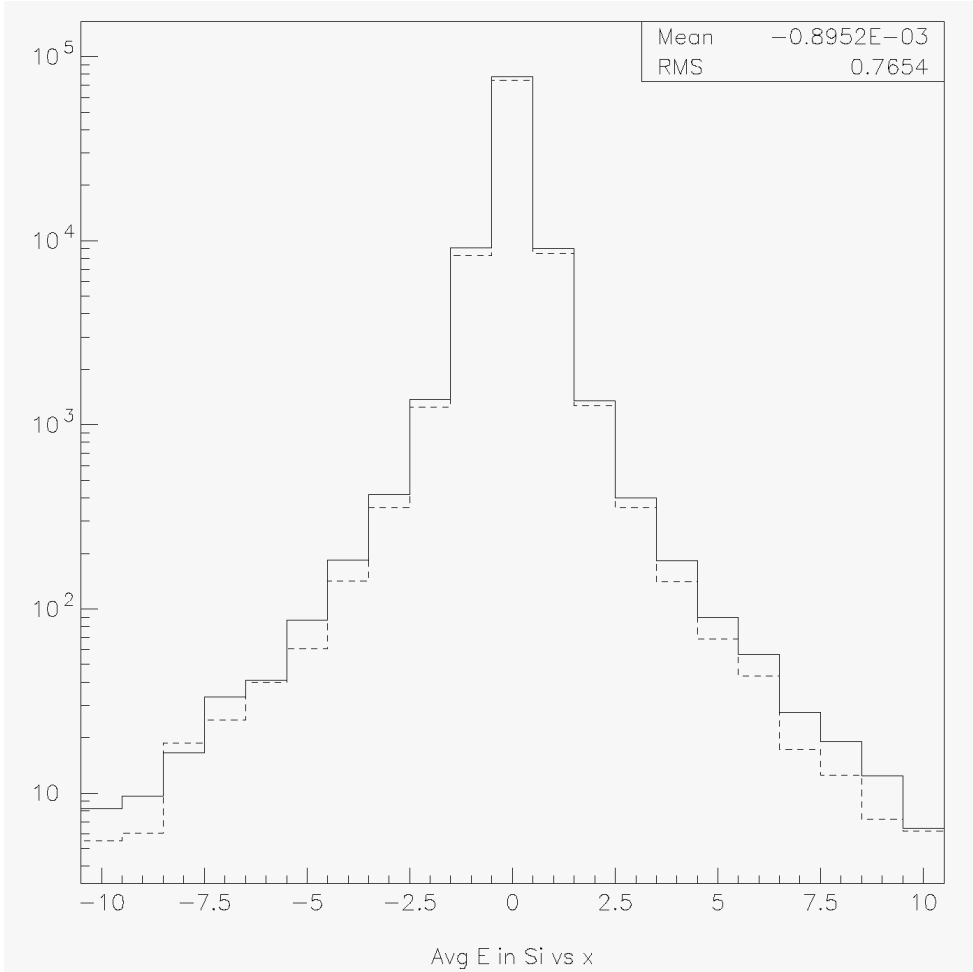


E vs x at layer 4

Note: rms is 0.44 pixel (2,2 mm)

E vs x: all layers

About a 20-25% difference



Superb Position Resolution for 1 GeV Photons

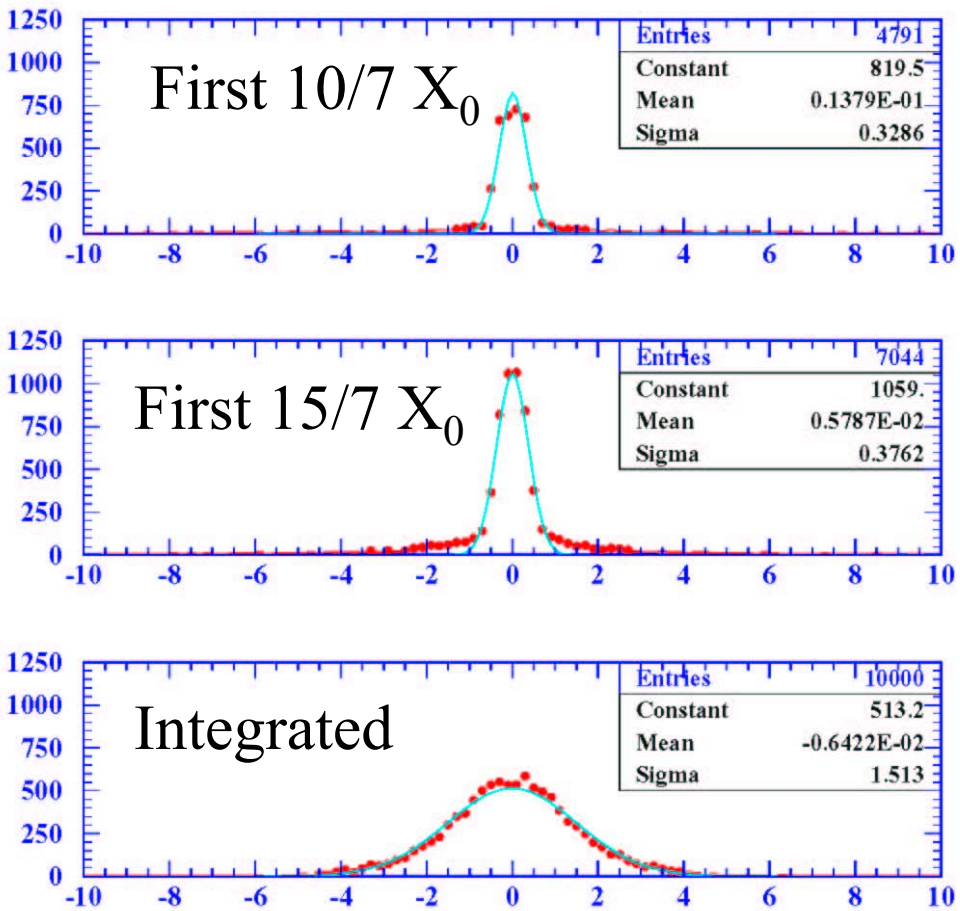
For illustration purposes only !:

Si-W, 42 layers,
1mm x 1mm pixels,

R_M = 13.5 mm

1 GeV photons

Transverse segmentations much finer than 5 mm may be useful – Si strips ?



330 μm

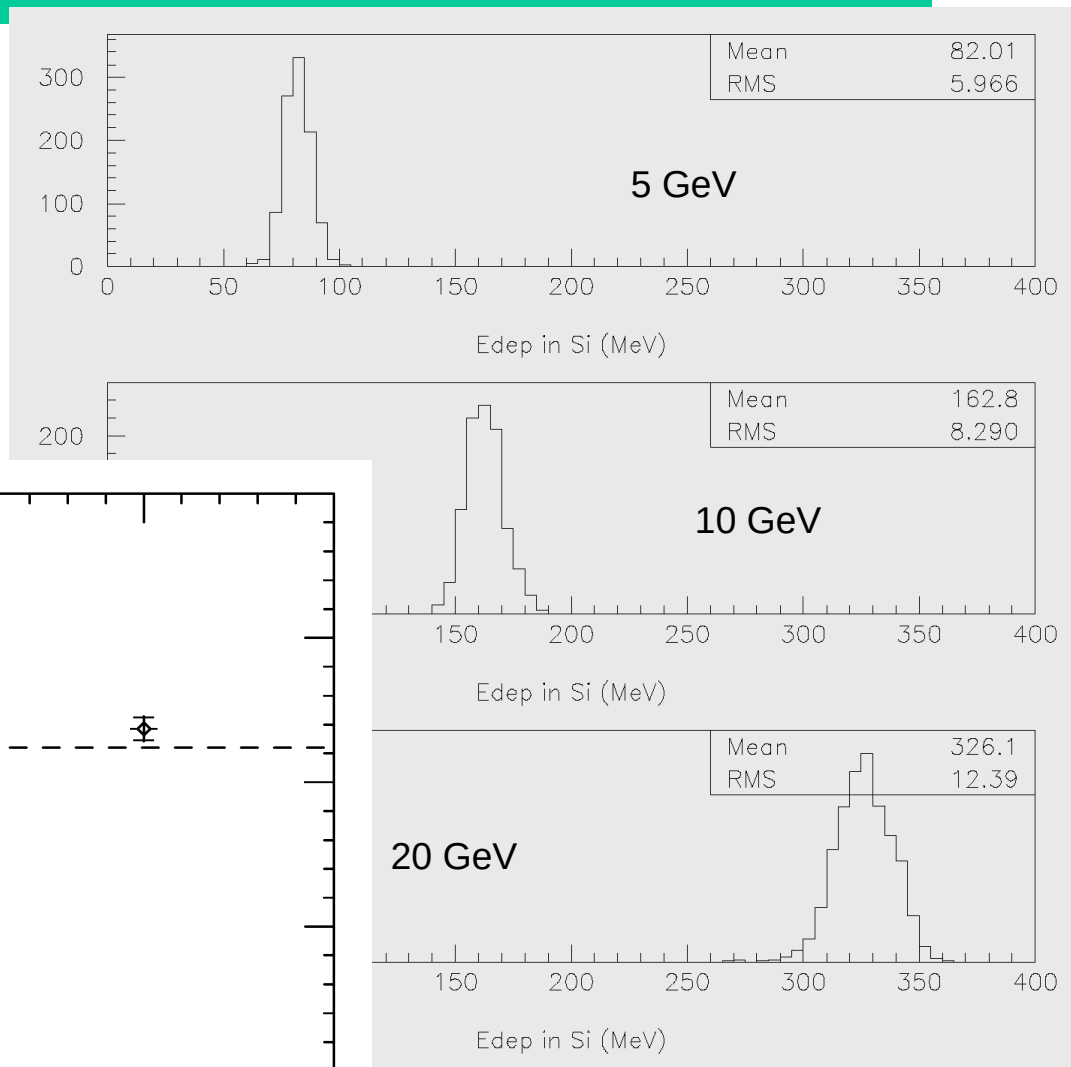
380 μm

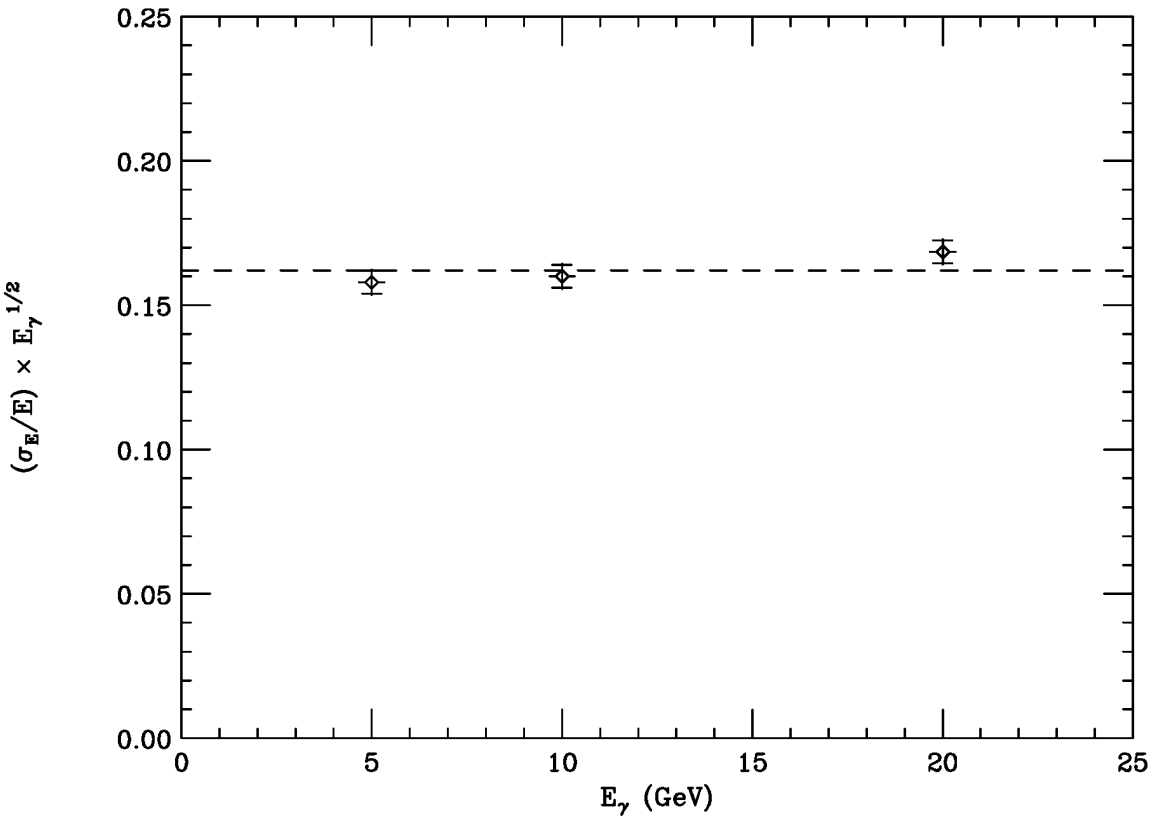
1500 μm

energy resolution (photons)

use rms for width:

$0.16/\sqrt{E}$



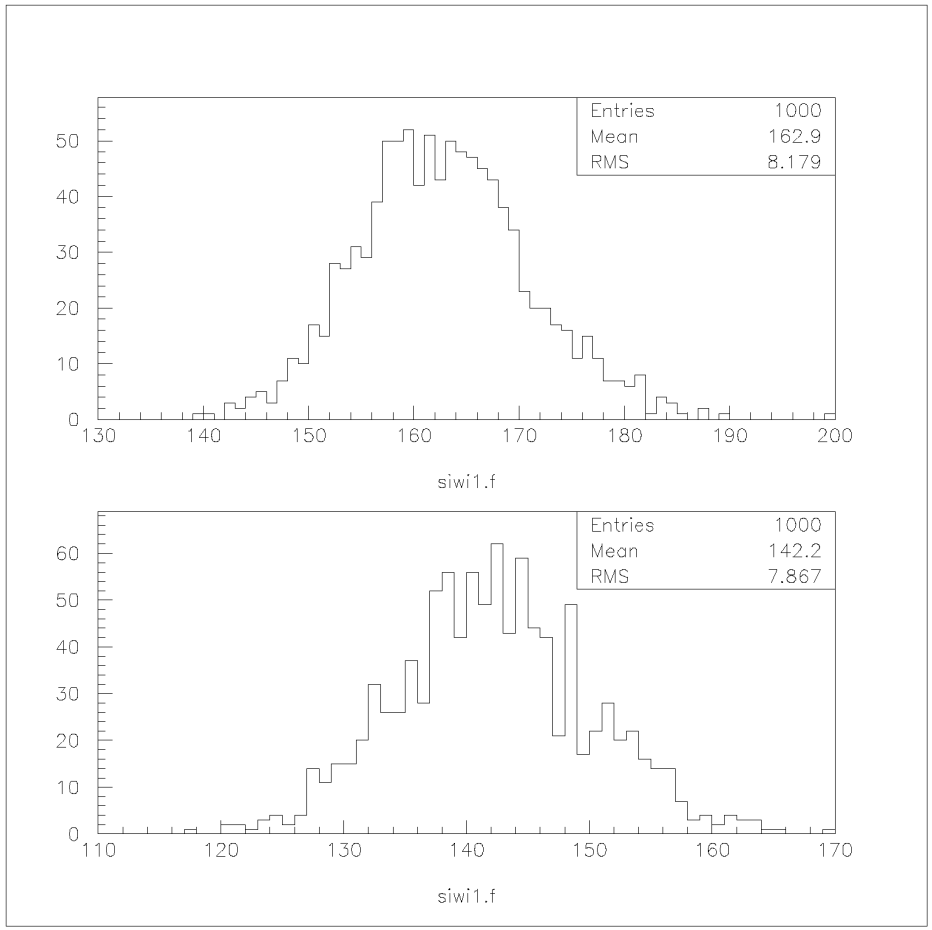


Compare with Geant4
N. Graf, G. Wilson, RF

- Used infinite planes of 2.5 mm W + 1mm G10 + 0.4mm Si
- Found that Geant4 with (standard?) 1mm range cut underestimated the energy deposited in the silicon by 15-20% (and hence the standard Geant4 gets poorer energy resolution)
- Found that the two converged for a Geant4 range cut of 0.1mm (or about 1 KeV equiv. energy cutoff)
- CPU time increases by factor 30

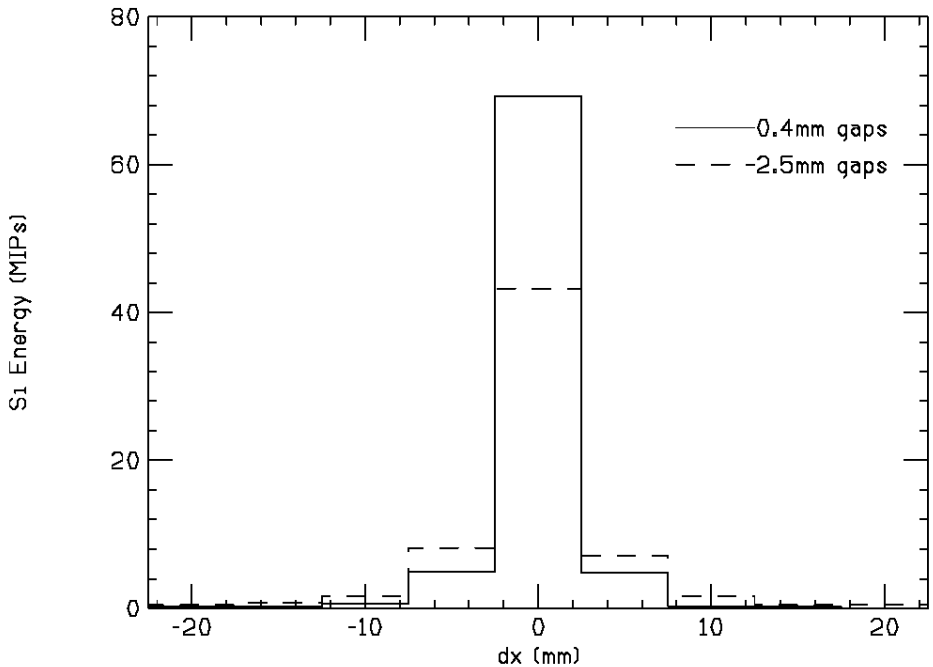
EGS4/Geant4 contd

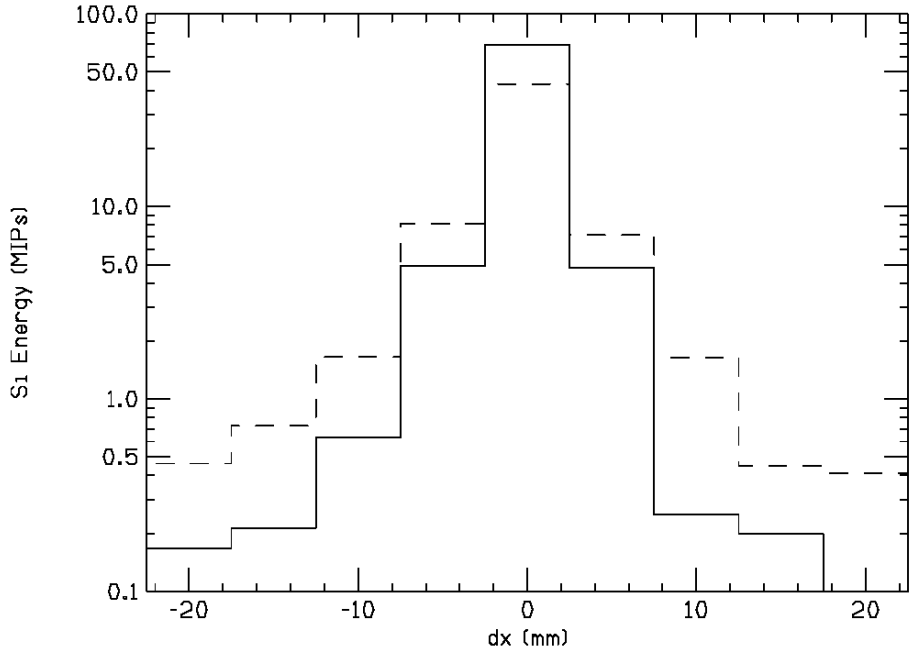
• Can make EGS approximate Geant4 with 1mm range cut by removing the skins and changing energy step from 0.3% (upper plot) to 2% (lower)



Effective Moliere radius - old

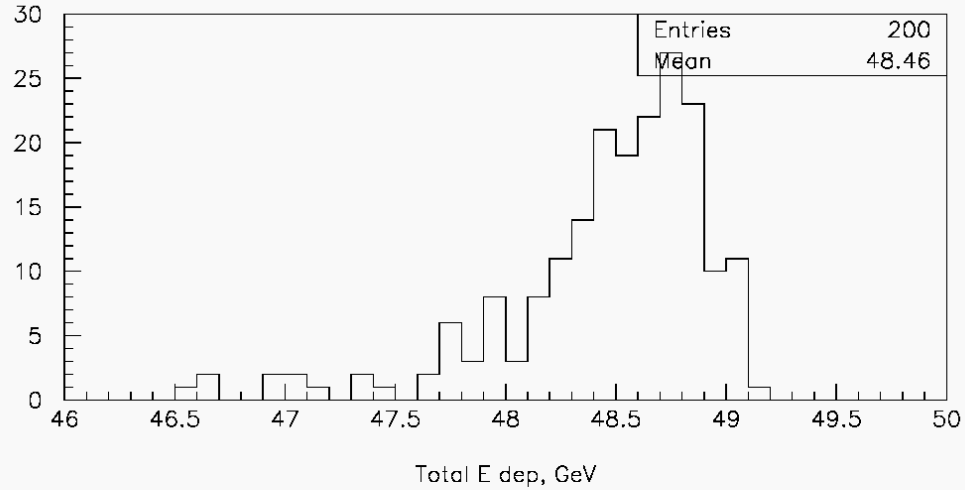
- Standard SD: 5x5 mm^2 pixels with (1) 0.4mm or (2) 2.5mm readout gaps.
- 10 GeV photons; look at layer 10



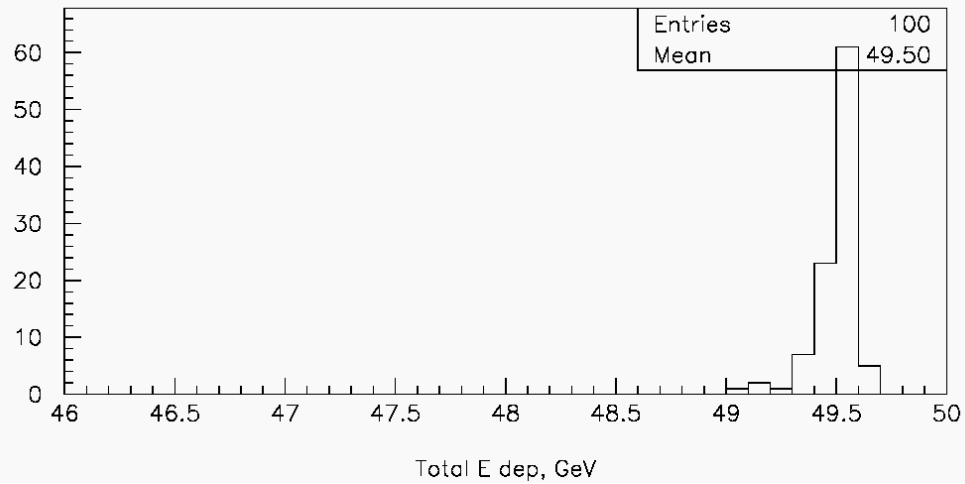


Alternative Sampling Configurations – old study

50 GeV electrons



30 x 5/7 X_0



20 x 5/7 X_0 + 10 x 10/7 X_0

- better containment
- poorer sampling